

**Low- T Transport Induced by Coulomb Interaction
in an Anderson Insulator**

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The Problem

$D \leq 2$: *ANDERSON LOCALIZATION*

+ *ELECTRON-ELECTRON INTERACTION*

at vanishing coupling to the external world (phonons, etc.)

Temperature $T \neq 0$: Conductivity $\sigma(T) = ?$

NO INTERACTION $\implies \sigma(T) \equiv 0$ FOR $\forall T$

TEMPERATURE: DISTRIBUTION OVER *LOCALIZED* STATES

$\sigma(T)$ is (possibly) nonzero due to e-e interaction only !

Electron-Electron Interactions in 2D and 1D

- High T + interaction: strong dephasing $L_\phi \ll \xi$
- ▷ singular weak localization corrections $\Delta\sigma_{\text{WL}} \propto L_\phi^{2-d}$
cut off by e-e scattering, L_ϕ
- Low T + interaction: strong localization

Key issue: $\sigma(T)$, or the fate of dephasing
in the strongly localized regime

▷ *Variable-Range Hopping ?*

History of the Problem: First There Was ...

- “Phononless Hopping” \equiv VRH due to e-e scattering
Fleishman, Licciardello & Anderson '78
- No VRH with e-e scattering for short-range interaction
Fleishman & Anderson '80

Interaction between electrons $V(r) \propto r^{-\gamma}$

$$\gamma + 2 > d : \sigma = 0$$

Coulomb: $\gamma = 1 \rightarrow d = 3$ –critical dimensionality

Short-range:	$\sigma = 0$
Long-range:	standard VRH
Critical:	?

Fleishman & Anderson '80

Outline:

- ▷ *Localization vs interaction-induced dephasing in 2D and quasi-1D: $\sigma(T)$ in the regime of strong localization*
- ▷ *Localization & dephasing in 1D: disordered Luttinger liquid*
- ▷ *Role of the “long-rangeness” of Coulomb interaction*

Phys. Rev. Lett. 95, 046404 (2005)

Phys. Rev. Lett. 95, 206603 (2005)

Model and Parameters

- **Weak short-range e-e interaction,**
 $\alpha \equiv \nu V_{q=0} \ll 1$ ← our main parameter
- **Weak white-noise disorder** $\langle UU \rangle_{q=0} = \frac{1}{2\pi\nu\tau}$, $\epsilon_F\tau \gg 1$
- $\Delta_\xi \ll \tau^{-1} \ll \epsilon_F$, $\Delta_\xi = 1/\nu\xi^d$ – level spacing in the localization volume

For definiteness → Thick (many-channel) quantum wire

On the metallic side: $|\Delta\sigma_{\text{WL}}|/\sigma_{\text{D}} \sim L_\phi/\xi \sim (T/T_1)^{-1/3}$

$$\tau_\phi^{-1} \sim \Delta_\xi (T/T_1)^{2/3}$$

$T < T_1 = \Delta_\xi/\alpha^2 \longrightarrow \tau_\phi^{-1} < \Delta_\xi$: localization strong

Intermediate T : Power-Law Hopping

*cf. Gogolin, Mel'nikov & Rashba '75 (phonons)
Basko '03 (dynamical localization)*

$T_3 < T < T_1$: Strong localization, but $\sigma(T)$ – power-law
(not exponential) function of T

$T_1 = \Delta_\xi / \alpha^2$: $\tau_\phi^{-1} \sim \Delta_\xi$ – single-particle level spacing

$T_3 = \Delta_\xi / \alpha$: $\tau_\phi^{-1} \sim \Delta_\xi^{(3)} = \Delta_\xi^2 / T$ – three-particle level spacing
in the localization volume

Diffusion over strongly overlapped localized states:

$$\sigma(T) \sim \sigma_{\text{ac}}(\Omega = i/\tau_\phi) \sim e^2 \nu \xi^2 / \tau_\phi$$

$$\tau_\phi^{-1} \sim |V|^2 / \Delta_\xi^{(3)} \sim \alpha^2 T \leftarrow \text{still from the Golden Rule}$$

$T < T_3$: Breakdown of the Perturbative Scheme

(Lifetime of localized states)⁻¹ : $\tau_{\phi}^{-1} \sim V^2 / \Delta_{\xi}^{(3)} < \Delta_{\xi}^{(3)}$
Matrix element of interaction
with energy transfer $\sim \Delta_{\xi}$: $V \sim \alpha \Delta_{\xi} < \Delta_{\xi}^{(3)}$

No decay at the Golden Rule level !

$\sigma_{VRH} = 0$ *Fleishman & Anderson '80*

Metal-Insulator Transition ?

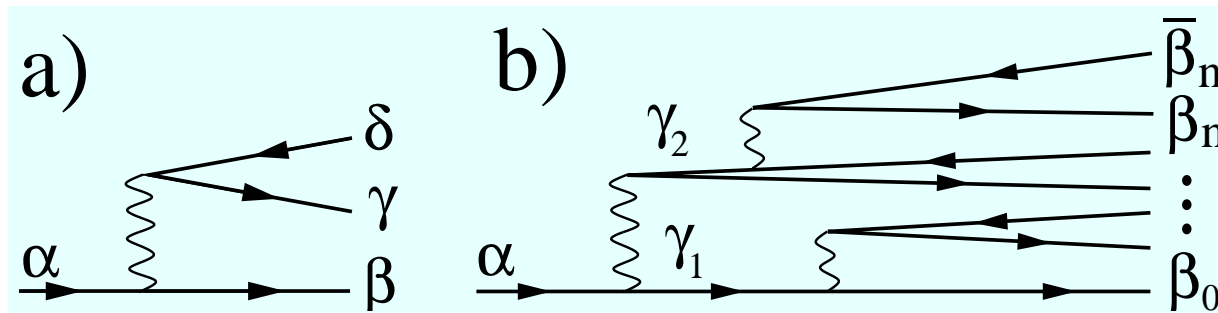
Many-Particle Hopping ?

cf. Altshuler, Gefen, Kamenev & Levitov '97 (quantum dots)

$T < T_3 \longrightarrow$ higher-order $V^{(n)} / \Delta^{(2n+1)}$

$|V^{(n)}| / \Delta^{(2n+1)} \ll 1$: shifts energy levels ($\text{Re}\Sigma$), but no real transitions

$|V^{(n)}| / \Delta^{(2n+1)} > c \sim 1$, all $n > n_*$: $\text{Im}\Sigma$ appears \Leftrightarrow real transitions



$$V^{(n)} = \sum_{\text{diagrams}} \sum_{\gamma_1, \dots, \gamma_{n-1}} V_1 \prod_{i=1}^{n-1} \frac{V_{i+1}}{E_i - \epsilon_{\gamma_i}}$$

Ballistic Electron-Hole Strings

Parametrize the n -th order process by (n, m) :

$m\xi$ – size of the region occupied by n e-h pairs ($1 \lesssim m \lesssim n$)

$$\Delta^{(2n+1)} \sim \Delta_\xi \left(\frac{n}{m} \frac{\Delta_\xi}{T} \right)^n$$

$$V^{(n)} \sim \alpha^n \Delta_\xi \left[M_m^{(n)} \right]^{1/2}$$

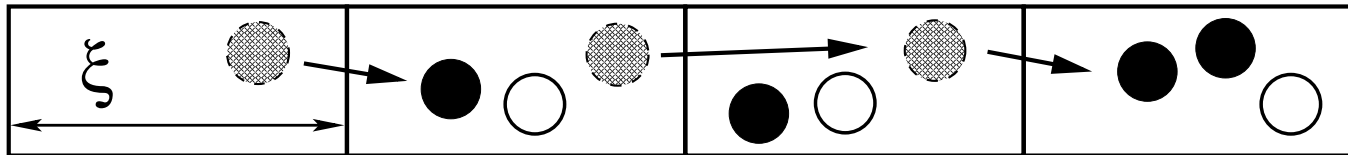
Multiplicativity $M_m^{(n)} \sim (n/m)^n$

$$\frac{V^{(n)}}{\Delta^{(2n+1)}} \sim \left[\alpha \left(\frac{m}{n} \right)^{1/2} \frac{T}{\Delta_\xi} \right]^n$$

Optimal paths \rightarrow ballistic ($m \sim n$) strings of e-h pairs

Gornyi, Mirlin & Polyakov: cond-mat/0407305; PRL '05

Error in $(n!)$ in the earlier version: Acknowledgment to
D.Basko, I.Aleiner & B.Altshuler



Metal-Insulator Transition

Main contribution to the higher-order coupling constant:

Ballistic strings of e-h pairs $\rightarrow |V^{(n)}|/\Delta^{(2n+1)} \sim (T/T_3)^n$

Critical temperature $T_c \sim T_3$: $\sigma(T < T_c) = 0$

Gornyi, Mirlin & Polyakov: PRL 95, 206603 (2005)

Basko, Aleiner & Altshuler: cond-mat/0506617
for weakly coupled granules

Critical behavior of $\sigma(T)$: Ballistic strings \equiv Bethe lattice

$$\ln \sigma(T) \propto 1/(T - T_c)^{1/2}$$

Gornyi, Mirlin & Polyakov: PRL 95, 206603 (2005)

Anderson-Fock glass: Mapping onto the Bethe lattice

Interacting problem in Fock space

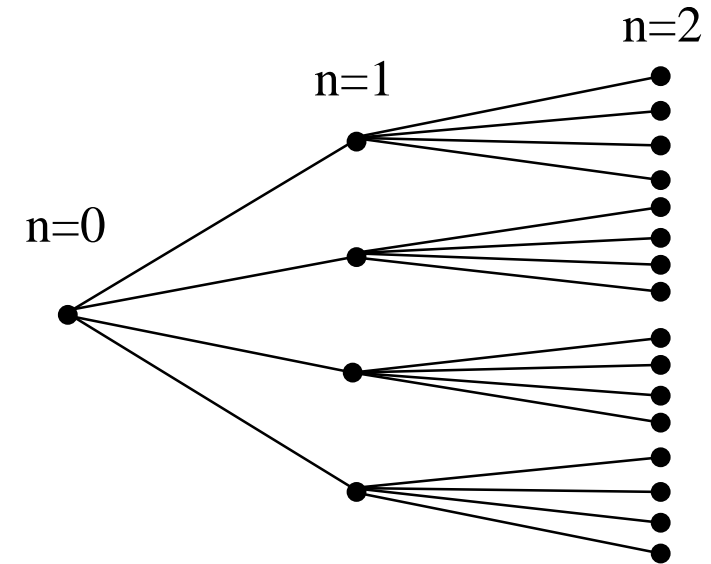
→ Ballistic e-h strings

→ nonint. Anderson problem on Bethe lattice *Abou-Chacra*

→ Metal-Insulator Transition at $\Delta/V = 4 \ln K$ *et al. '73*

Branching # : $K \sim \frac{\Delta_\xi}{\Delta_\xi^{(3)}} \sim \frac{T}{\Delta_\xi} \gg 1$

$$\Delta \rightarrow \Delta_\xi^{(3)} \quad V \rightarrow \alpha \Delta_\xi$$



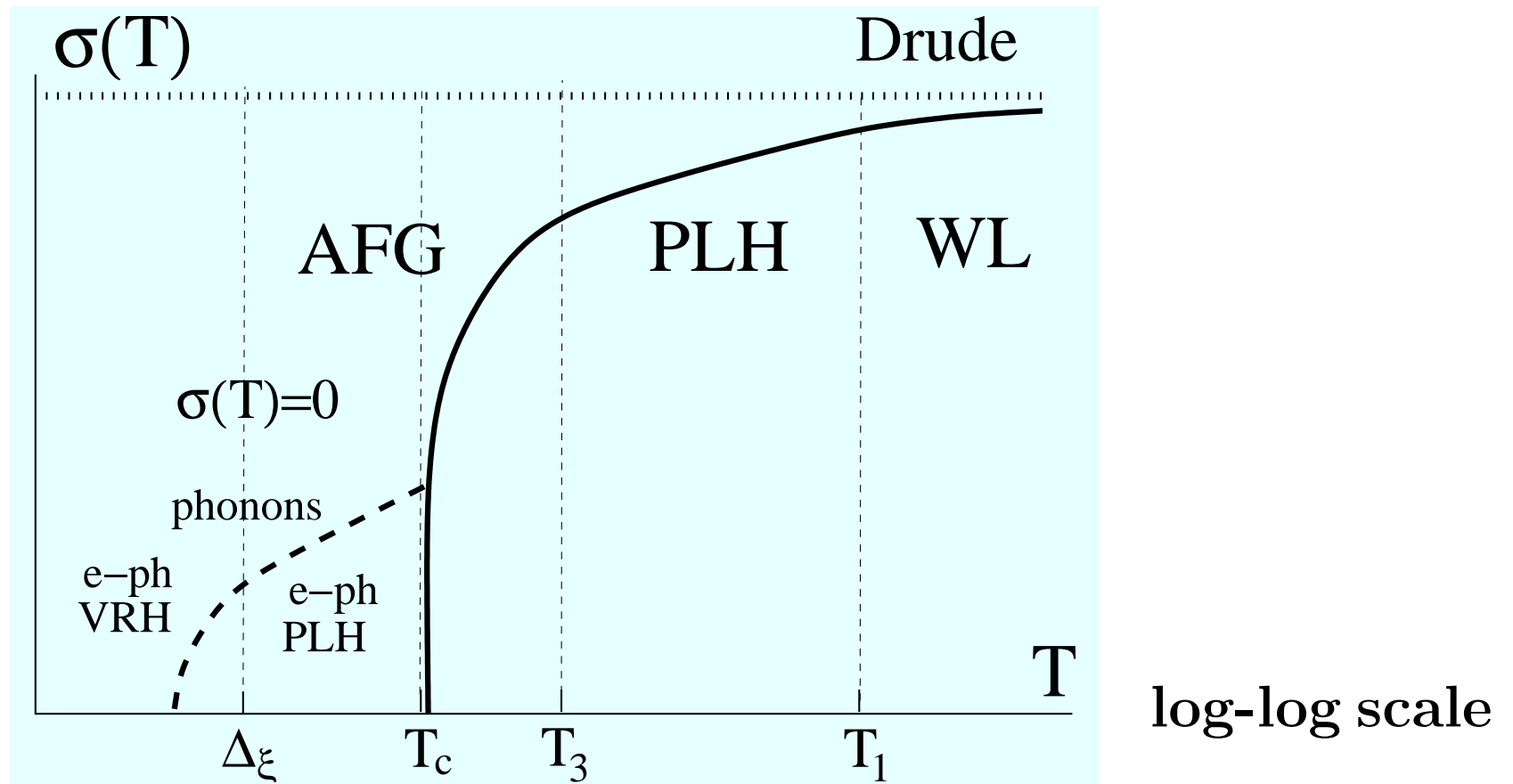
Transition at $T_c \sim \frac{\Delta_\xi}{\alpha \ln(1/\alpha)}$

Critical behavior $\sigma(T) \propto \tau_\phi^{-1} \propto \exp \left[-c_\alpha \left(\frac{T_c}{T - T_c} \right)^{1/2} \right]$

Zirnbauer, Efetov, Mirlin/Fyodorov

$$c_\alpha \sim \ln \alpha^{-1}$$

Absence of Diffusion in Certain Random Lattices,
Even at Finite Temperature



*Interaction-induced dephasing rate $\tau_\phi^{-1} = 0$
 between $T = 0$ and T_c*

Mesoscopics of single-channel quantum wires

- Interaction, no disorder: *Luttinger liquid*
Conventional wisdom: Non-Fermi liquid
Proper language = Bosons (density field)
- Fermi liquid + disorder: $\sigma(T) \rightarrow T > T_c$: entirely due to dephasing
- Luttinger liquid + disorder: $\sigma(T) = ?$

Fermi-quasiparticle breakdown \Rightarrow

Key issue: What is dephasing in Luttinger liquid,
or,

Are the notions of mesoscopics applicable to Luttinger liquid?

Weak-localization correction to the conductivity
of Luttinger liquid :

$$\sigma_{\text{WL}} = -2\sigma_{\text{D}} \int_0^\infty dt \int_0^\infty dt_a P(t, t_a) \exp[-S(t, t_a)]$$

$P \sim 1/\tau^2$ – probability density of return

$S \sim (t/\tau_\phi)^2$ – dephasing action

Dephasing of weak localization in Luttinger liquid: Results

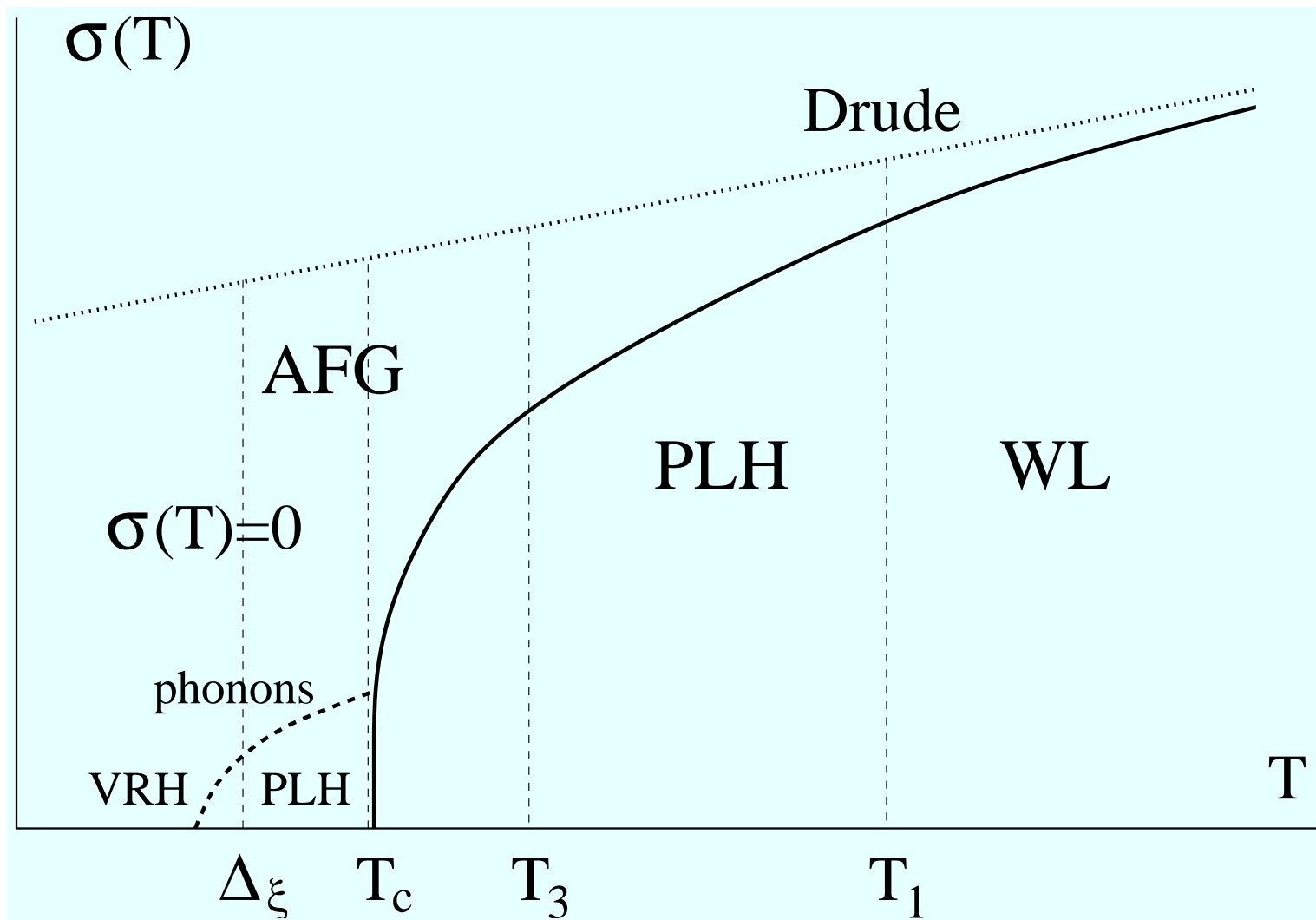
Gornyi, Mirlin & Polyakov, PRL 95, 046404 (2005)

Localization
correction :

$$\sigma = -\frac{1}{4}\sigma_D \left(\frac{\tau_\phi}{\tau}\right)^2 \ln \frac{\tau}{\tau_\phi} \propto \frac{1}{\alpha^2 T} \ln(\alpha^2 T)$$

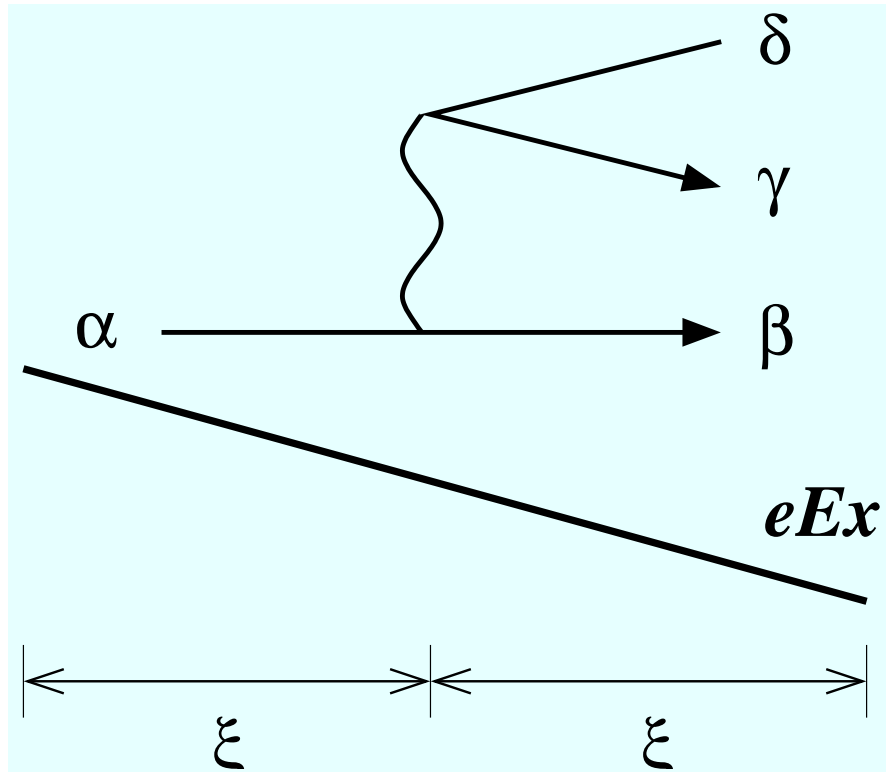
$$\text{Dephasing rate : } 1/\tau_\phi = \alpha(\pi T/\tau)^{1/2}$$

- “ τ_ϕ^{-1} in 1D: Fermi-liquid approach inapplicable” ← wrong
- $\tau^{-1}(T) \sim \tau_0^{-1}(\epsilon_F/T)^{2\alpha}$ – strongly T -dependent τ and ξ
- *dephasing of spinless electrons:*
 - ▷ $\tau_\phi^{-1} \propto \tau^{-1/2} \ll \tau_{ee}^{-1}$ – (lifetime)⁻¹ of particles in clean Lutt. liquid
 - ▷ $\delta\tau_\phi^{-1} \sim \alpha^2 T^2 / m v_F^2$, $m^{-1} = \text{curvature}$
- *dephasing of spinful electrons:*
 - ▷ $\tau_\phi^{-1} \sim \alpha T \propto |u_c - u_s|^{-1}$ – singular in spin-charge separation



log-log scale

Creep



“Effective temperature”

$$T \rightarrow eE\xi$$

Three-particle DoS
for transitions between
neighboring localization volumes

$$\nu^{(3)} \sim eE/\Delta_{\xi}^2$$

Threshold in electric field : $E_c \sim \frac{1}{e\xi} \frac{\Delta_{\xi}}{\alpha \ln(1/\alpha)}$

Creep for $E > E_c$: $\ln \sigma(E) \propto 1/(E - E_c)^{1/2}$

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Transport Mediated by Coulomb Interaction

Screening within the loc. volume: $\kappa(q \sim \xi^{-1}) \sim (\xi/\lambda_s)^{d-1}$

Matrix element between **neighboring** states :

$$\text{Before: } V \sim \alpha \Delta_\xi$$

$$\text{Now: } V \sim \frac{e^2}{\xi \kappa(q \sim \xi^{-1})} \sim \Delta_\xi, \quad \alpha \sim 1 \text{ (caution!)}$$

Coupling between **neighboring** states only \rightarrow

$$\text{Transition at } T = T_c \sim \Delta_\xi$$

Are e_*^2/r tails of screened Coulomb interaction important ?

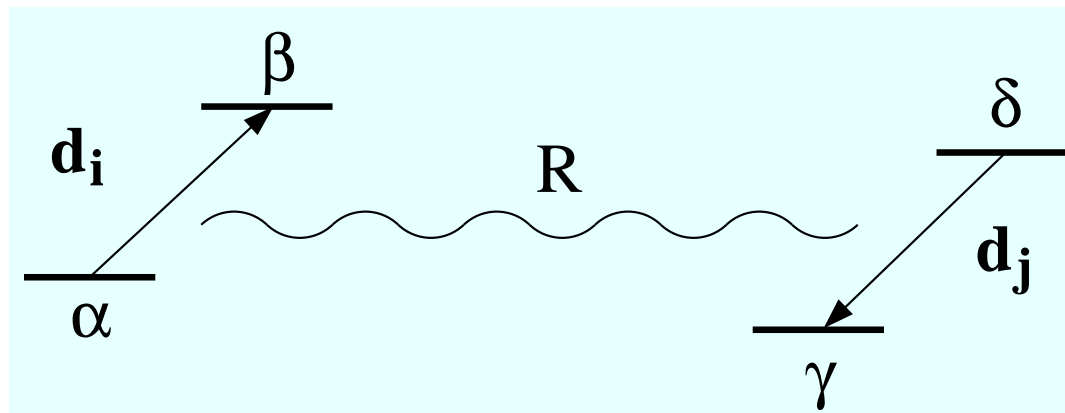
Transport Mediated by Coulomb Interaction (cont'd)

Matrix element between distant states :

particle \longrightarrow 2 (distant) particles + hole: dipole-dipole interaction

$$V_{ij} = \frac{d_i d_j}{R^3} - \frac{3(d_i R)(d_j R)}{R^5}$$

between two e-h pairs with dipole moments d_i and d_j



$$d_{\alpha\beta} \rightarrow (r_\alpha - r_\beta) I_{\alpha\beta} / |\omega_{\alpha\beta}| \propto \exp(-|r_\alpha - r_\beta|/\xi)$$

Transport Mediated by Coulomb Interaction (cont'd)

Dipole-dipole interaction $V_{ij} = \frac{d_i d_j}{R^3} - \frac{3(d_i R)(d_j R)}{R^5}$

Coupling constant for $e \rightarrow 2e+h$ decay: $c(R) = \nu p^2 \int dR/R^3$

(probability of a dipole-dipole resonance within radius R)

$$p \propto \exp[-(T_0/T)^{1/2}] \quad , \quad T_0 \sim e_*^2/\xi$$

$d = 3$ – critical dimensionality: $c(R) = \nu p^2 \ln(R/l_h)$

$$l_h \sim \xi(T_0/T)^{1/2} \text{ – hopping length}$$

Distance R_c between resonating pairs: $c(R_c) \sim 1$

$$\tau_\phi^{-1} \sim V \propto R_c^{-3} \propto \exp(-\#/\nu p^2)$$

$$\# \sim 1 \text{ – from percolation theory}$$

$$\ln \ln \sigma \sim -(T_0/T)^{1/2}$$

Summary

TRANSPORT INDUCED BY ELECTRON-ELECTRON INTERACTIONS IN DISORDERED SYSTEMS

- *Anderson-Fock Glass, $\sigma(T < T_c) = 0$*
- *Dephasing in Luttinger liquid :
Mesoscopics of strongly correlated systems*
- *Coulomb-interaction mediated transport
in 3D Anderson insulators : Double-exp behavior*